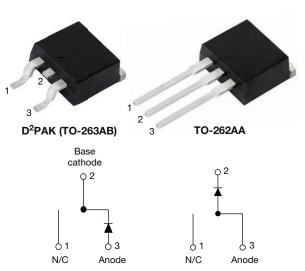
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VS-8ETH06S-M3

VS-8ETH06-1-M3

PRIMARY CHARACTERISTICS				
I _{F(AV)}	8 A			
V _R	600 V			
V _F at I _F	1.3 V			
t _{rr} typ.	18 ns			
T _J max.	175 °C			
Package	D ² PAK (TO-263AB), TO-262AA			
Circuit configuration	Common cathode			

FEATURES

- · Hyperfast recovery time
- · Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Peak repetitive reverse voltage	V _{RRM}		600	V	
Average rectified forward current	I _{F(AV)}	T _C = 144 °C	8		
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	90	А	
Peak repetitive forward current	I _{FM}		16		
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C	

ELECTRICAL SPEC	IFICATIO	NS ($T_J = 25 \ ^{\circ}C$ unless otherwise specified	(k				
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
Forward voltage	VF	I _F = 8 A	-	2.0	2.4	V	
Forward voltage	۷F	I _F = 8 A, T _J = 150 °C	-	1.3	1.8		
Reverse leakage current	1-	$V_{R} = V_{R}$ rated	-	0.3	50		
neverse leakage current	I _R	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	55	500	μA	
Junction capacitance	CT	V _R = 600 V	-	17	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH	

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HALOGEN

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DYNAMIC RECOVERY CHARAC	TERISTIC	S (T _C = 25 °C un	less otherwise sp	ecified)			
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 1$	00 A/µs, V _R = 30 V	-	18	22	
Reverse recovery time	+	$I_F = 8 A$, $dI_F/dt = 1$	00 A/µs, V _R = 30 V	-	20	25	ns
neverse recovery time	t _{rr}	T _J = 25 °C		-	25	-	115
		T _J = 125 °C		-	40		
Peak recovery current	1	T _J = 25 °C	l _F = 8 A dl _F /dt = 200 A/μs	-	2.4	-	А
Fear recovery current	I _{RRM}	T _J = 125 °C	$V_{\rm B} = 390 \text{ V}$	-	4.8	-	~
Poweree receivery charge	0	T _J = 25 °C		-	25	-	nC
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	120	-	ne
Reverse recovery time	t _{rr}		I _F = 8 A	-	33	-	ns
Peak recovery current	I _{RRM}	T _J = 125 °C	Γ _J = 125 °C dI _F /dt = 600 A/μs	-	12	-	А
Reverse recovery charge	Q _{rr}		V _R = 390 V	-	220	-	nC

THERMAL - MECHANICAL SPE	CIFICATIO	DNS				
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance, junction to case per leg	R _{thJC}		-	1.4	2	
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount	-	-	70	°C/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.5	-	
Weight			-	2.0	-	g
Weight			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking davias		Case style D ² PAK (TO-263AB)	8ETH06S			
Marking device		Case style TO-262AA		8ETH	106-1	

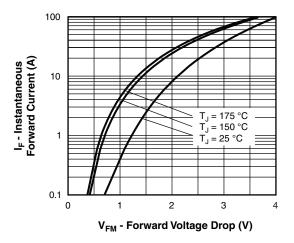
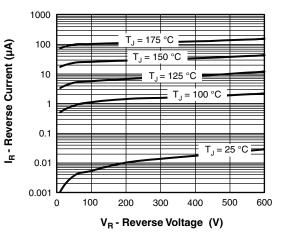
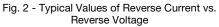


Fig. 1 - Maximum Forward Voltage Drop Characteristics





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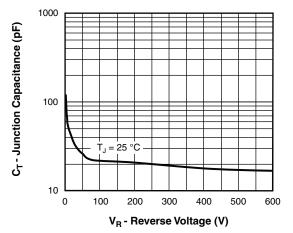


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

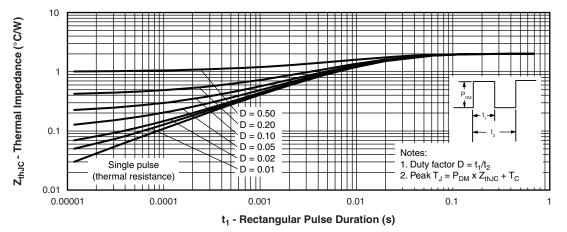
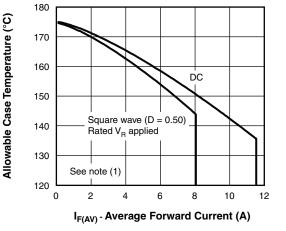
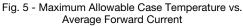


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

Average Power Loss (W)





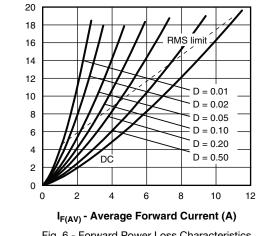


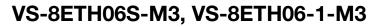
Fig. 6 - Forward Power Loss Characteristics

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dl_F/dt (A/µs)

Fig. 8 - Typical Stored Charge vs. dl_F/dt

400

350

300

250

200

150 100

50

0

100

Q_{rr} (nC)

V_R = 390 V

T_J = 125 °C

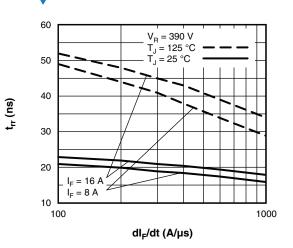
I_F = 16 A

 $I_F = 8 A$

T₁ = 25 °C

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Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

Note

SHA

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC};$
 - $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{I} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

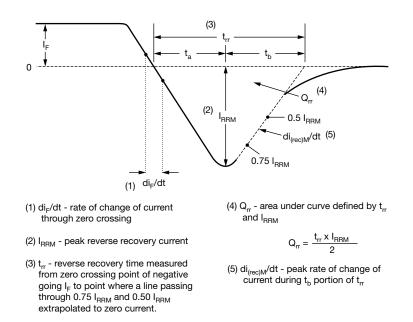
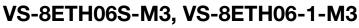


Fig. 9 - Reverse Recovery Waveform and Definitions

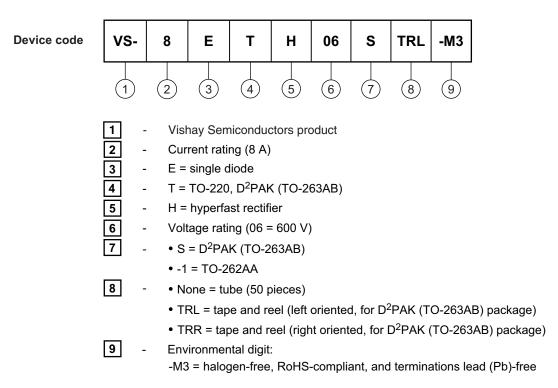


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ORDERING INFORMATION TABLE

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	LINKS TO RELATE	D DOCUMENTS
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164
Dimensions	TO-262AA	www.vishay.com/doc?96165
Port morking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444
Part marking information	TO-262AA	www.vishay.com/doc?95443
Packaging information	D ² PAK (TO-263AB)	www.vishay.com/doc?96424

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D²PAK

DIMENSIONS in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
A	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
		MIN.	MAX.	MIN.	MAX.	NOTES
	D1	6.86	8.00	0.270	0.315	3
	E	9.65	10.67	0.380	0.420	2, 3
	E1	7.90	8.80	0.311	0.346	3
	е	2.54 BSC		0.100 BSC		
	Н	14.61	15.88	0.575	0.625	
	L	1.78	2.79	0.070	0.110	
	L1	-	1.65	-	0.066	3
	L2	1.27	1.78	0.050	0.070	
	L3	0.25 BSC		0.010	BSC	
	L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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Document Number: 96164

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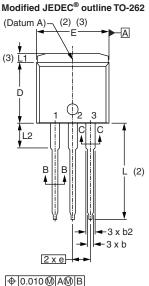
Outline Dimensions

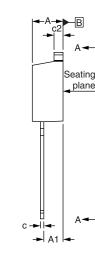


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TO-262AA

DIMENSIONS in millimeters and inches





F D1 (3) (3) Section A - A Base (4) Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None





Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode

Lead assignments

SYMBOL	MILLIN	IETERS	INC	HES	NOTES	
STNIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D		8.51 9.65	9.65	0.335	0.380	2
D1		8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	BSC	0.100) BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

 ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
 ⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the second dimensioner of the second dimensis and the second dimensioner of the second dimensioner of the the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only (5)

Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

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